NSN 5961-01-351-3756

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-351-3756 **Inclosure Material:** Plastic **Overall Length:** Between 0.240 inches and 0.255 inches **Terminal Length:** 1.000 inches **Overall Diameter:** Between 0.120 inches and 0.127 inches **Function For Which Designed:** Transient suppressor **Mounting Method: Terminal Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 7.37 breakdown voltage, dc **Current Rating Per Characteristic:** 10.00 milliamperes forward current, total rms nanoamperes **Power Rating Per Characteristic:** 500.0 watts small-signal input power, common-collector major **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

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